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FQP6N60C/FQPF6N60C 600V N-Channel MOSFET

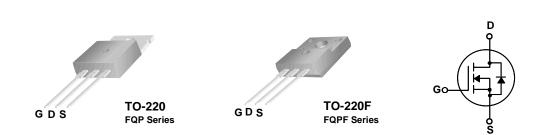
General Description

These N-Channel enhancement mode power field effect transistors are produced using Fairchild's proprietary, planar stripe, DMOS technology.

This advanced technology has been especially tailored to minimize on-state resistance, provide superior switching performance, and withstand high energy pulse in the avalanche and commutation mode. These devices are well suited for high efficiency switched mode power supplies, active power factor correction, electronic lamp ballasts based on half bridge topology.

Features

- + 5.5A, 600V, $R_{DS(on)}$ = 2.0 Ω @V_{GS} = 10 V + Low gate charge (typical 16 nC)
- Low Crss (typical 7 pF) •
- Fast switching
- · 100% avalanche tested
- · Improved dv/dt capability



Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter		FQP6N60C	FQPF6N60C	Units
V _{DSS}	Drain-Source Voltage		600		V
I _D	Drain Current - Continuous ($T_C = 25^{\circ}C$)		5.5	5.5 *	А
	- Continuous (T _C = 100°C)		3.3	3.3 *	А
I _{DM}	Drain Current - Pulsed (Note 1)		22	22 *	А
V _{GSS}	Gate-Source Voltage		± 30		V
E _{AS}	Single Pulsed Avalanche Energy (No		300		mJ
I _{AR}	Avalanche Current	(Note 1)	5.5		А
E _{AR}	Repetitive Avalanche Energy (Note 1)		12.5		mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)		4.5		V/ns
P _D	Power Dissipation ($T_C = 25^{\circ}C$)		125	40	W
	- Derate above 25°C		1.0	0.31	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150		°C
TL	Maximum lead temperature for soldering purposes,		300		°C
۲L	1/8" from case for 5 seconds				
Orain current lim	nited by maximum junction temperature.			· · · · ·	

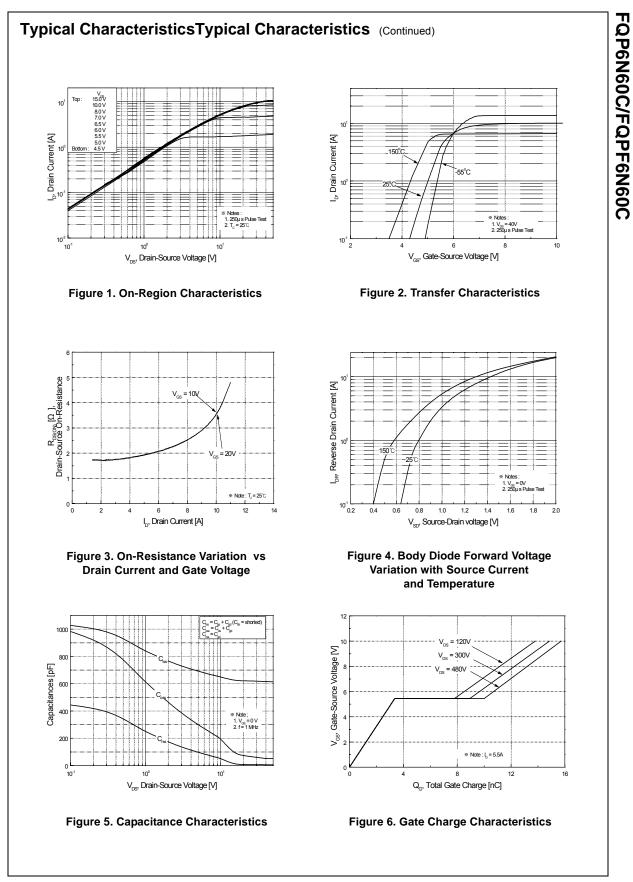
Thermal Characteristics

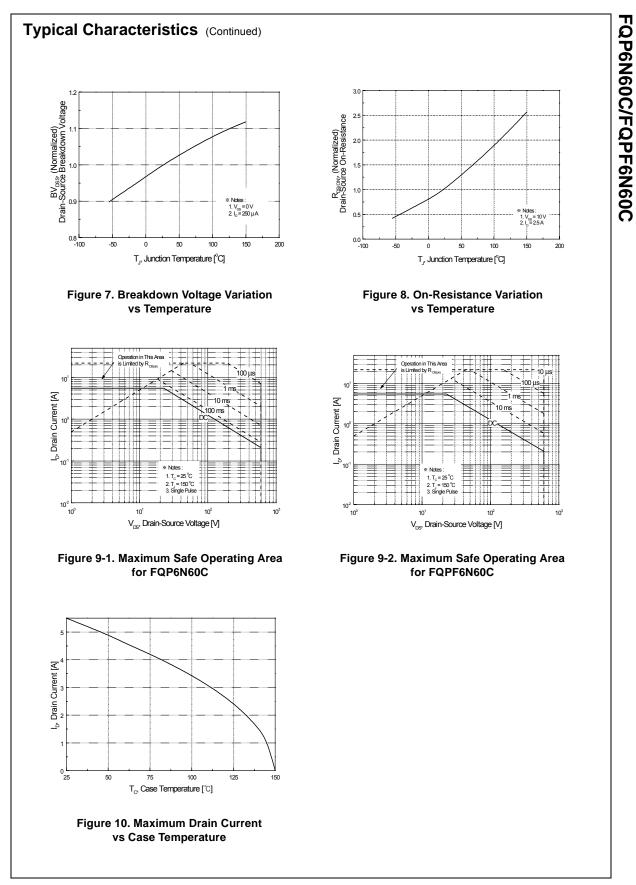
Symbol	Symbol Parameter		FQPF6N60C	Units	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	1.0	3.2	°C/W	
$R_{\theta CS}$	Thermal Resistance, Case-to-Sink Typ.	0.5		°C/W	
R _{0JA} Thermal Resistance, Junction-to-Ambient		62.5	62.5	°C/W	

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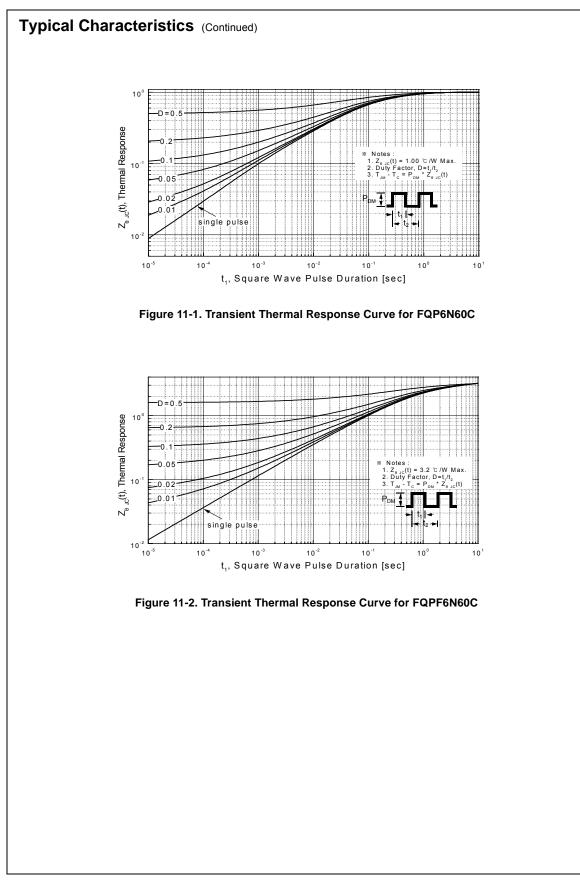
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Symbol	Parameter	Parameter Test Conditions		Тур	Max	Units
Off Cha	aracteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0 V, I _D = 250 μA	600			V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, Referenced to 25°C		0.6		V/°C
I _{DSS}	Zana Cata Maltana Duain Current	V _{DS} = 600 V, V _{GS} = 0 V			1	μA
	Zero Gate Voltage Drain Current	V _{DS} = 480 V, T _C = 125°C			10	μA
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 30 V, V _{DS} = 0 V			100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	V_{GS} = -30 V, V_{DS} = 0 V			-100	nA
On Cha	aracteristics					
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = 250 μA	2.0		4.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = 10 V, I _D = 2.75 A		1.7	2.0	Ω
9 _{FS}	Forward Transconductance	$V_{DS} = 40 \text{ V}, \text{ I}_{D} = 2.75 \text{ A}$ (Note 4)		4.8		S
	ic Characteristics		1		010	
C _{iss}	Input Capacitance	$V_{DS} = 25 V, V_{GS} = 0 V,$		620	810	pF
C _{oss} C _{rss}	Output Capacitance Reverse Transfer Capacitance	f = 1.0 MHz		65 7	85 10	pF pF
d(on)	Turn-On Delay Time	V _{DD} = 300 V, I _D = 5.5A,		15	40	ns
	ing Characteristics			15	40	ne
t _r	Turn-On Rise Time	$R_G = 25 \Omega$		45	100	ns
t _{d(off)}	Turn-Off Delay Time			45	100	ns
t _f	Turn-Off Fall Time	(Note 4, 5)		45	100	ns
Qg	Total Gate Charge	V _{DS} = 480 V, I _D = 5.5A,		16	20	nC
Q _{gs}	Gate-Source Charge	V _{GS} = 10 V		3.5		nC
Q _{gd}	Gate-Drain Charge	(Note 4, 5)		6.5		nC
	ource Diode Characteristics a				1	1
I _S	Maximum Continuous Drain-Source Die				5.5	A
I _{SM}	Maximum Pulsed Drain-Source Diode F				22	A
V _{SD}	Drain-Source Diode Forward Voltage				1.4	V
t _{rr}	Reverse Recovery Time	$V_{GS} = 0 V, I_{S} = 5.5 A,$		310		ns
Q _{rr}	Reverse Recovery Charge	dI _F / dt = 100 A/µs (Note 4)		2.1		μC
L = 18.2mH, $I_{SD} \le 5.5A$, o Pulse Test :	$ \begin{array}{l} \mbox{tating}: \mbox{Pulse width limited by maximum junction tempe} \\ I_{AS} = 5.5 \mbox{A}, V_{DD} = 50V, R_G = 25 \ \Omega, \mbox{Starting } T_J = 25^{\circ} \\ \mbox{didt} \leq 200A/\mu s, \ V_{DD} \leq BV_{DSS}, \mbox{Starting } T_J = 25^{\circ}C \\ \mbox{Pulse width} \leq 300\mu s, \ Duty \ cycle \leq 2\% \\ \mbox{ndependent of operating temperature} \end{array} $					

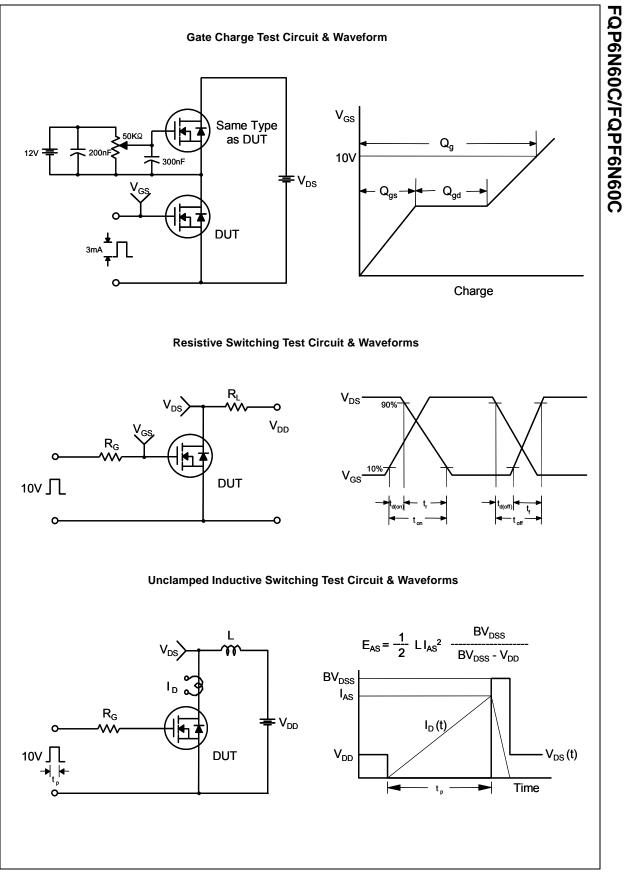


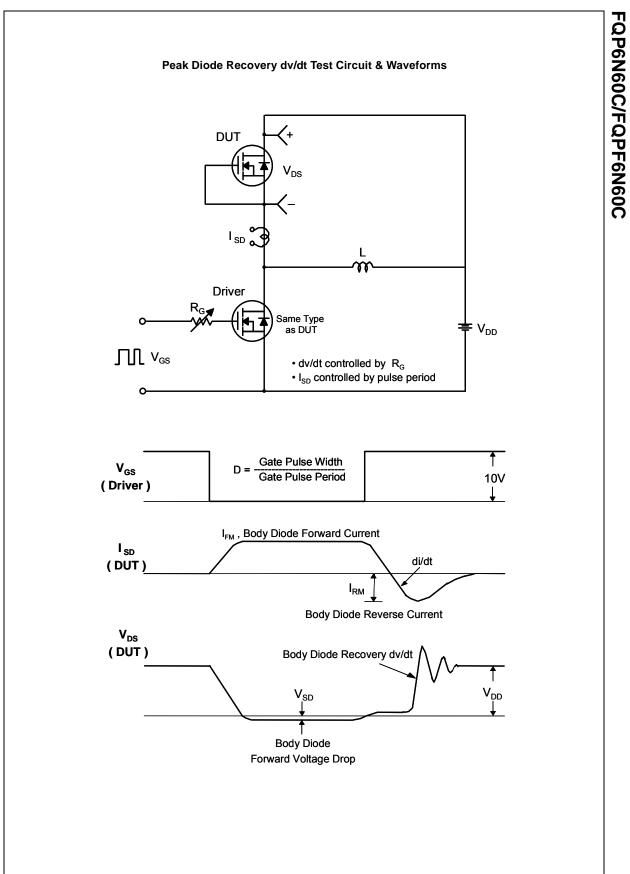


Rev. A, March 2004

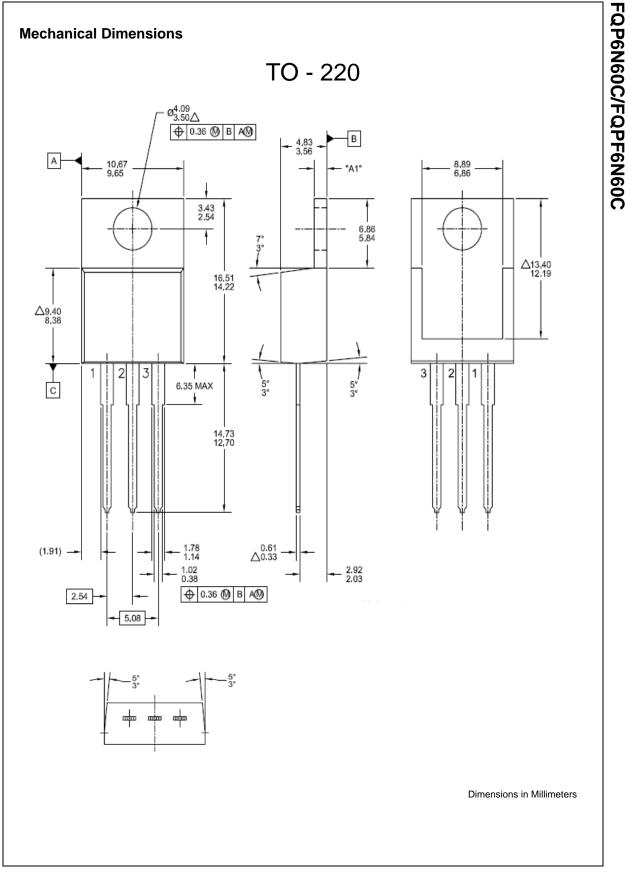


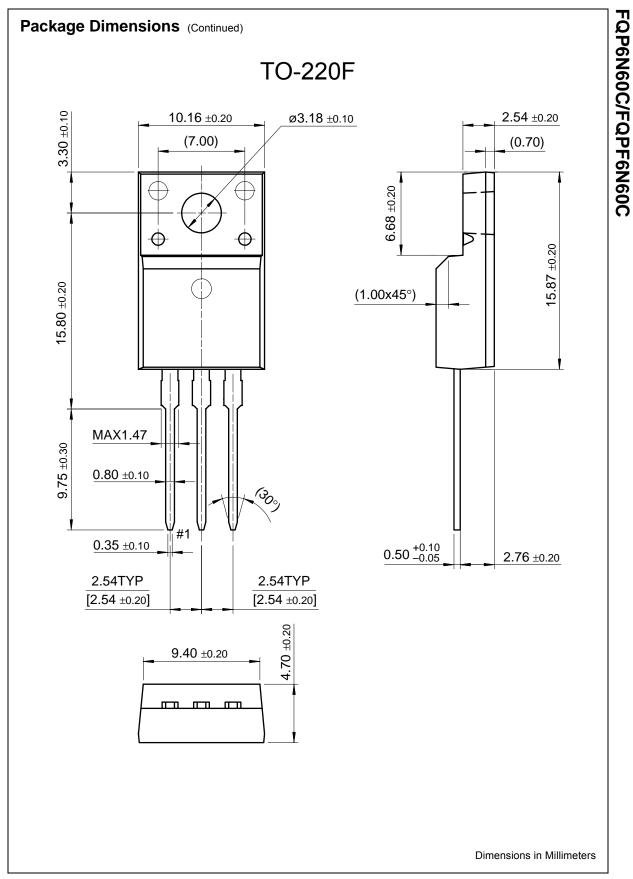
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Rev. A, March 2004





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